MMQA Quad Common Anode Series

Preferred Devices

SC-74 Quad Monolithic Common Anode

Transient Voltage Suppressors for ESD Protection

This quad monolithic silicon voltage suppressor is designed for applications requiring transient overvoltage protection capability. It is intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment, and other applications. Its quad junction common anode design protects four separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Specification Features:

- SC−74 Package Allows Four Separate Unidirectional Configurations
- Peak Power − Min. 24 W @ 1.0 ms (Unidirectional), per Figure 5 Waveform
- Peak Power − Min. 150 W @ 20 μs (Unidirectional), per Figure 6 Waveform
- Maximum Clamping Voltage @ Peak Pulse Current
- Low Leakage < 2.0 μA
- ESD Rating of Class N (exceeding 16 kV) per the Human Body Model
- Pb−Free Packages are Available

THERMAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

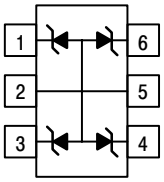
Characteristic	Symbol	Value	Unit
Peak Power Dissipation @ 1.0 ms (Note 1) @ $T_A \le 25°C$	P_{pk}	24	W
Peak Power Dissipation @ 20 μs (Note 2) @ $T_A \le 25°C$	P_{pk}	150	W
Total Power Dissipation on FR-5 Board (Note 3) @ T_A = 25°C	P_D	225 1.8	mW mW/°C
Thermal Resistance from Junction−to−Ambient	$R_{\theta JA}$	556	°C/W
Total Power Dissipation on Alumina Substrate (Note 4) @ T_A = 25°C Derate above 25°C	P_D	300 2.4	mW mW/°C
Thermal Resistance from Junction−to−Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature Range	T_J, T_{stg}	− 55 to +150	°C
Lead Solder Temperature − Maximum (10 Second Duration)	T_L	260	°C

ON Semiconductor®

http://onsemi.com

SC−74 QUAD TRANSIENT VOLTAGE SUPPRESSOR 24 WATTS PEAK POWER 5.6 − 33 VOLTS

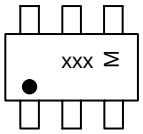
PIN ASSIGNMENT



PIN 1. CATHODE
2. ANODE
3. CATHODE
4. CATHODE
5. ANODE
6. CATHODE

SC−74
PLASTIC
CASE 318F

MARKING DIAGRAM



xxx = Device Code
M = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information in the table on page 5 of this data sheet.

DEVICE MARKING INFORMATION

See specific marking information in the device marking table on page 5 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)
UNIDIRECTIONAL
(Circuit tied to pins 1, 2, and 5; Pins 2, 3, and 5; Pins 2, 4, and 5; or Pins 2, 5, and 6) (V_F = 0.9 V Max @ I_F = 10 mA)

	Breakdown Voltage				Max Reverse Leakage Current		Max Zener Impedance (Note 7)	Max Reverse Surge Current	Max Reverse Voltage @ I_{RSM} (Note 6) (Clamping Voltage)	Maximum Temperature Coefficient of V_Z	Capacitance @ 0 Volt Bias, 1 MHz (pF)	
		V_{ZT} (Note 5) (V)		@ I_{ZT}	I_R	V_R						
Device	Min	Nom	Max	(mA)	(nA)	(V)	Z_{ZT} @ I_{ZT} (Ω) (mA)	I_{RSM} (A)	V_{RSM} (V)	(mV/°C)	Min	Max
MMQA5V6T1,T3	5.32	5.6	5.88	1.0	2000	3.0	400	3.0	8.0	1.26	–	–
MMQA6V2T1,T3	5.89	6.2	6.51	1.0	700	4.0	300	2.66	9.0	10.6	–	–
MMQA6V8T1,T3	6.46	6.8	7.14	1.0	500	4.3	300	2.45	9.8	10.9	100	250
MMQA12VT1,T3	11.4	12	12.6	1.0	75	9.1	80	1.39	17.3	14	–	–
MMQA13VT1	12.4	13	13.7	1.0	75	9.8	80	1.29	18.6	15	–	–
MMQA15VT1,T3	14.3	15	15.8	1.0	75	11	80	1.1	21.7	16	–	–
MMQA18VT1,T3	17.1	18	18.9	1.0	75	14	80	0.923	26	19	–	–
MMQA20VT1,T3	19	20	21	1.0	75	15	80	0.84	28.6	20.1	–	–
MMQA21VT1,T3	20	21	22.1	1.0	75	16	80	0.792	30.3	21	–	–
MMQA22VT1,T3	20.9	22	23.1	1.0	75	17	80	0.758	31.7	22	–	–
MMQA24VT1,T3	22.8	24	25.2	1.0	75	18	100	0.694	34.6	25	–	–
MMQA27VT1,T3	25.7	27	28.4	1.0	75	21	125	0.615	39	28	–	–
MMQA30VT1,T3	28.5	30	31.5	1.0	75	23	150	0.554	43.3	32	–	–
MMQA33VT1,T3	31.4	33	34.7	1.0	75	25	200	0.504	48.6	37	–	–

1. Non-repetitive current pulse per Figure 5 and derate above T_A = 25°C per Figure 4.
2. Non-repetitive current pulse per Figure 6 and derate above T_A = 25°C per Figure 4.
3. FR-5 = 1.0 x 0.75 x 0.62 in.
4. Alumina = 0.4 x 0.3 x 0.024 in., 99.5% alumina
5. V_Z measured at pulse test current I_T at an ambient temperature of 25°C.
6. Surge current waveform per Figure 5 and derate per Figure 4.
7. Z_{ZT} is measured by dividing the AC voltage drop across the device by the AC current supplied. The specified limits are $I_{Z(AC)}$ = 0.1 $I_{Z(DC)}$, with AC frequency = 1 kHz.

TYPICAL CHARACTERISTICS

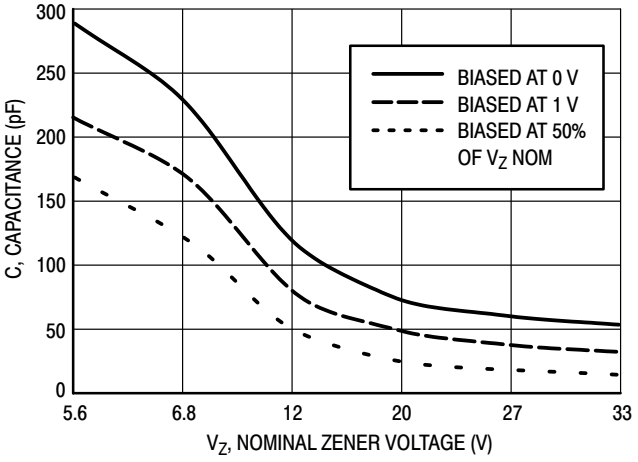


Figure 1. Typical Capacitance

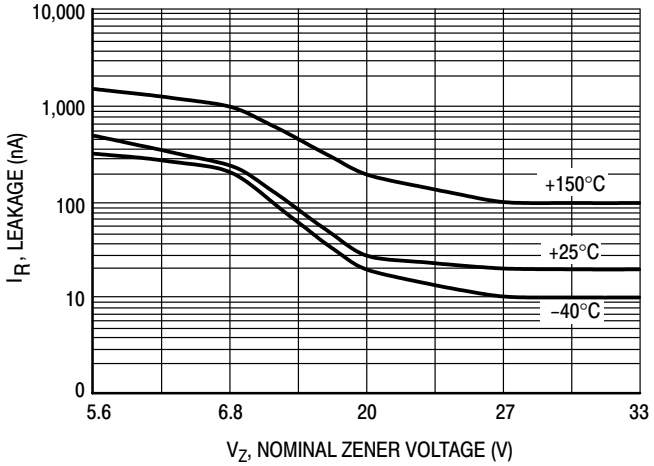


Figure 2. Typical Leakage Current

TYPICAL CHARACTERISTICS

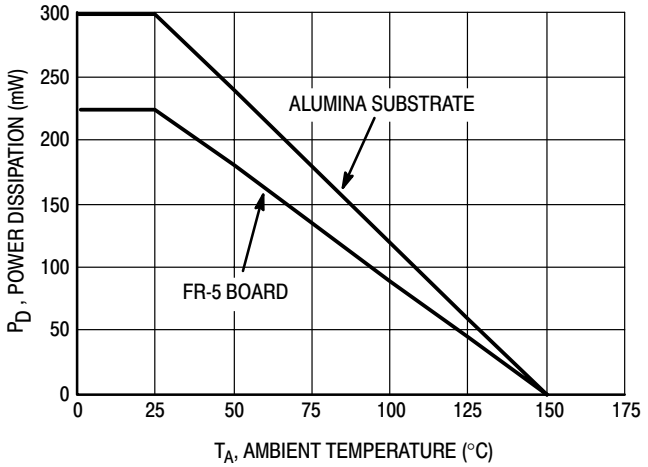


Figure 3. Steady State Power Derating Curve

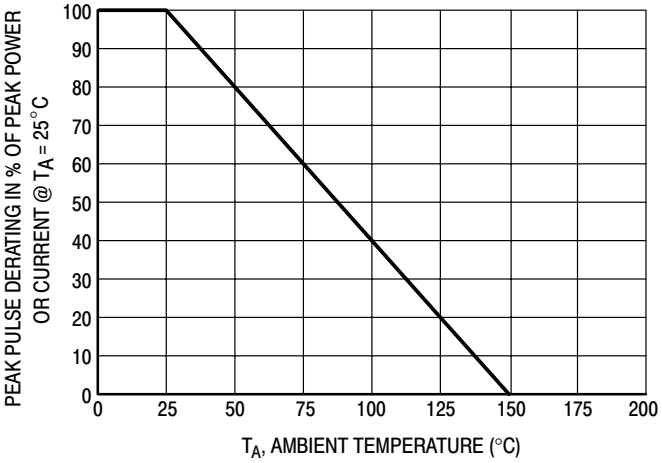


Figure 4. Pulse Derating Curve

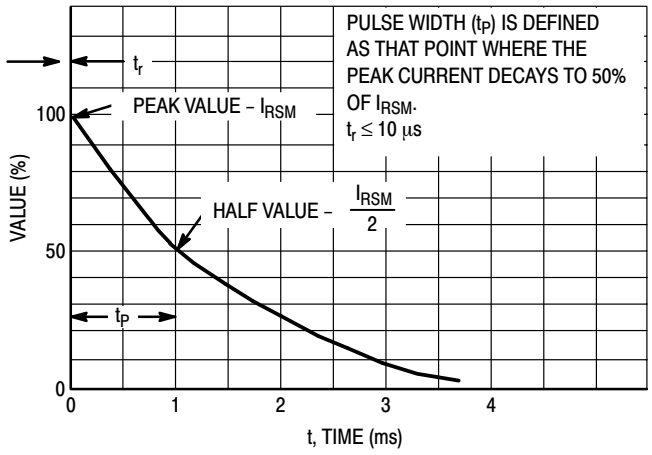


Figure 5. 10 × 1000 μs Pulse Waveform

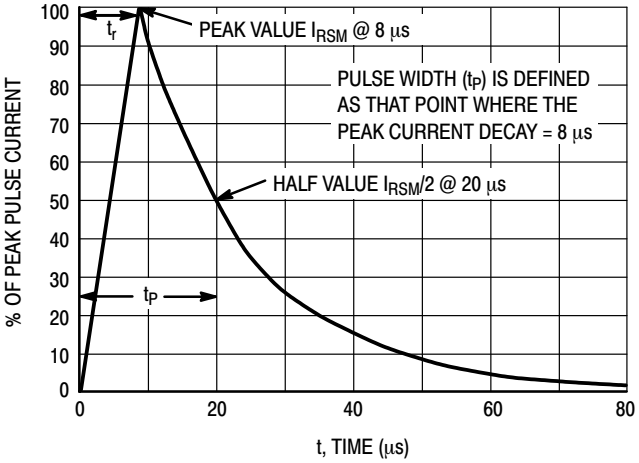


Figure 6. 8 × 20 μs Pulse Waveform

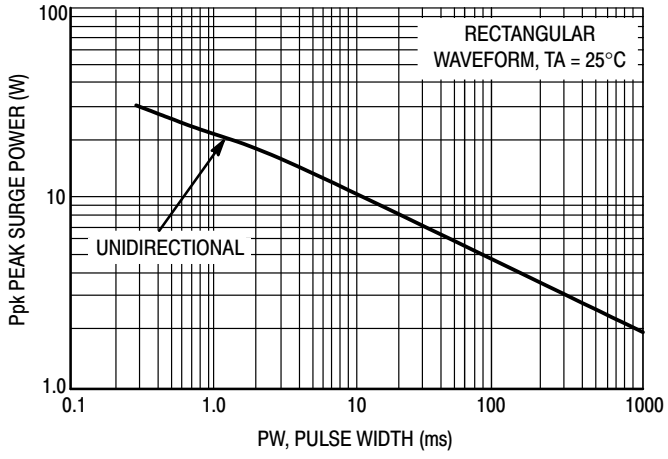


Figure 7. Maximum Non−Repetitive Surge Power, Ppk versus PW

Power is defined as V_{RSM} x I_Z(pk) where V_{RSM} is the clamping voltage at I_Z(pk).

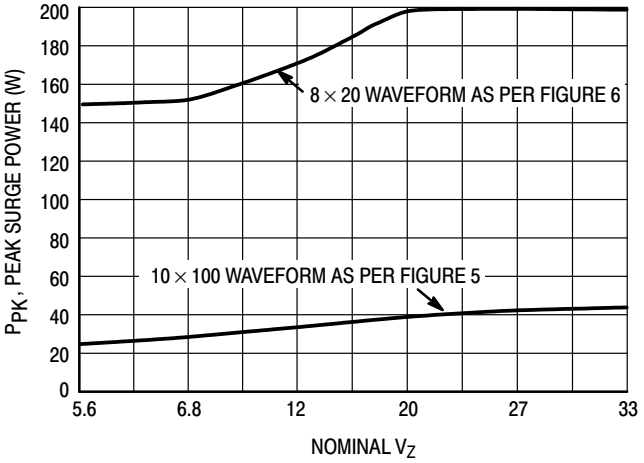
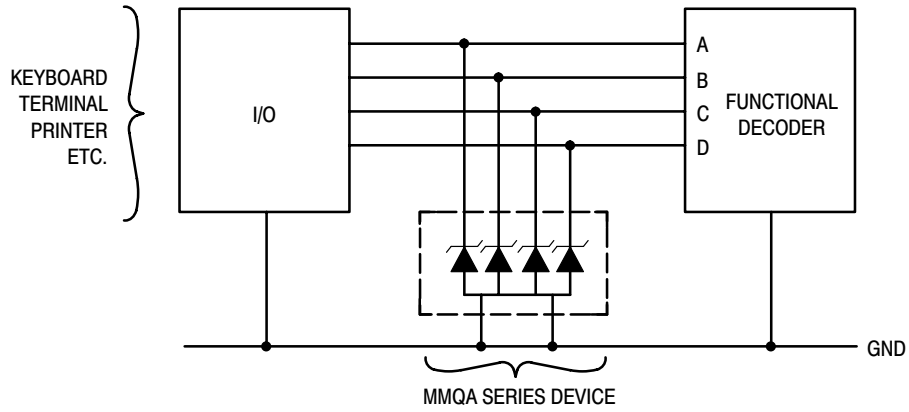


Figure 8. Typical Maximum Non−Repetitive Surge Power, Ppk versus V_{BR}

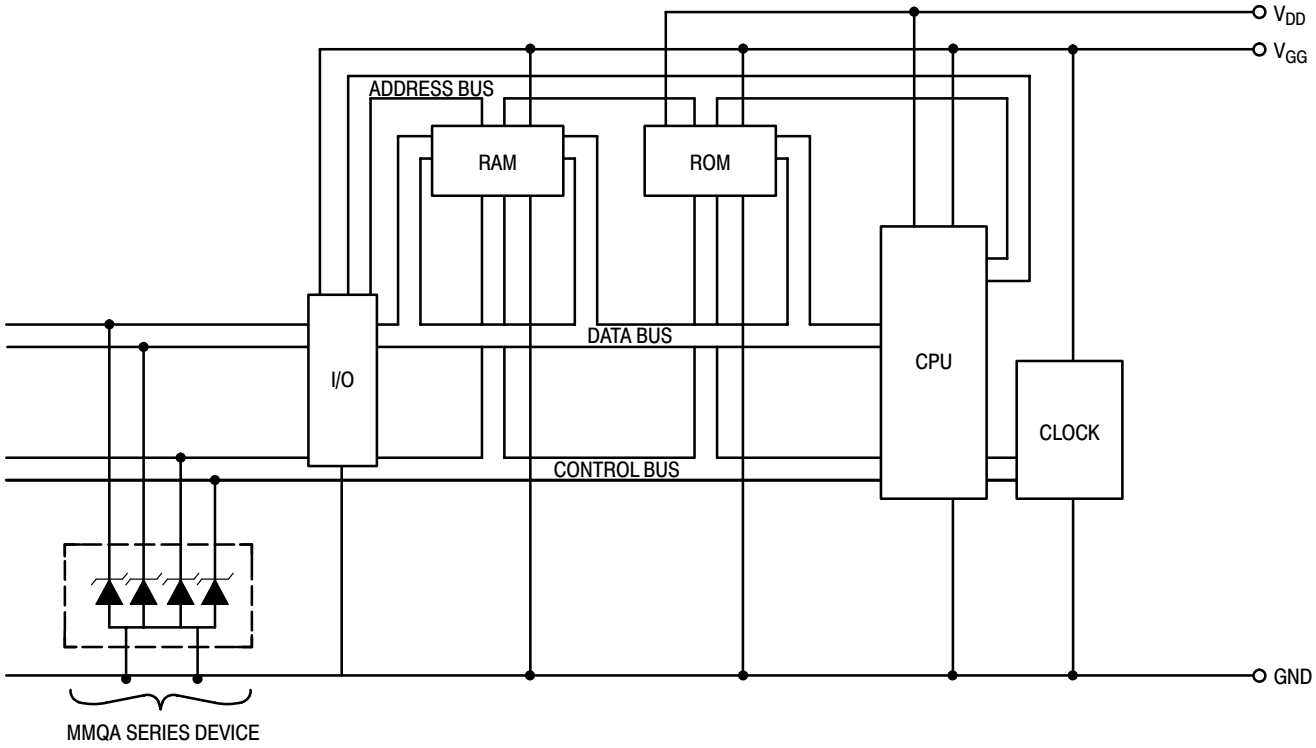
TYPICAL COMMON ANODE APPLICATIONS

A quad junction common anode design in a SC−74 package protects four separate lines using only one package. This adds flexibility and creativity to PCB design especially when board space is at a premium. A simplified example of MMQA Series Device applications is illustrated below.

Computer Interface Protection



Microprocessor Protection



DEVICE MARKING AND ORDERING INFORMATION

Device	Device Marking	Package	Shipping†
MMQA5V6T1	5A6	SC−74	3,000/Tape & Reel
MMQA5V6T3	5A6	SC−74	10,000/Tape & Reel
MMQA6V2T1	6A2	SC−74	3,000/Tape & Reel
MMQA6V2T1G	6A2	SC−74 (Pb−Free)	3,000/Tape & Reel
MMQA6V2T3	6A2	SC−74	10,000/Tape & Reel
MMQA6V8T1	6A8	SC−74	3,000/Tape & Reel
MMQA6V8T3	6A8	SC−74	10,000/Tape & Reel
MMQA12VT1	12A	SC−74	3,000/Tape & Reel
MMQA12VT1G	12A	SC−74 (Pb−Free)	3,000/Tape & Reel
MMQA12VT3	12A	SC−74	10,000/Tape & Reel
MMQA13VT1	13A	SC−74	3,000/Tape & Reel
MMQA15VT1	15A	SC−74	3,000/Tape & Reel
MMQA15VT3	15A	SC−74	10,000/Tape & Reel
MMQA18VT1	18A	SC−74	3,000/Tape & Reel
MMQA18VT3	18A	SC−74	10,000/Tape & Reel
MMQA20VT1	20A	SC−74	3,000/Tape & Reel
MMQA20VT3	20A	SC−74	10,000/Tape & Reel
MMQA20VT3G	20A	SC−74 (Pb−Free)	10,000/Tape & Reel
MMQA21VT1	21A	SC−74	3,000/Tape & Reel
MMQA21VT3	21A	SC−74	10,000/Tape & Reel
MMQA22VT1	22A	SC−74	3,000/Tape & Reel
MMQA22VT3	22A	SC−74	10,000/Tape & Reel
MMQA24VT1	24A	SC−74	3,000/Tape & Reel
MMQA24VT3	24A	SC−74	10,000/Tape & Reel
MMQA27VT1	27A	SC−74	3,000/Tape & Reel
MMQA27VT3	27A	SC−74	10,000/Tape & Reel
MMQA30VT1	30A	SC−74	3,000/Tape & Reel
MMQA30VT3	30A	SC−74	10,000/Tape & Reel
MMQA33VT1	33A	SC−74	3,000/Tape & Reel
MMQA33VT3	33A	SC−74	10,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic case.

FINISH: Corrosion resistant finish, easily solderable.

Package designed for optimal automated board assembly.

Small package size for high density applications.

Available in 8 mm Tape and Reel.

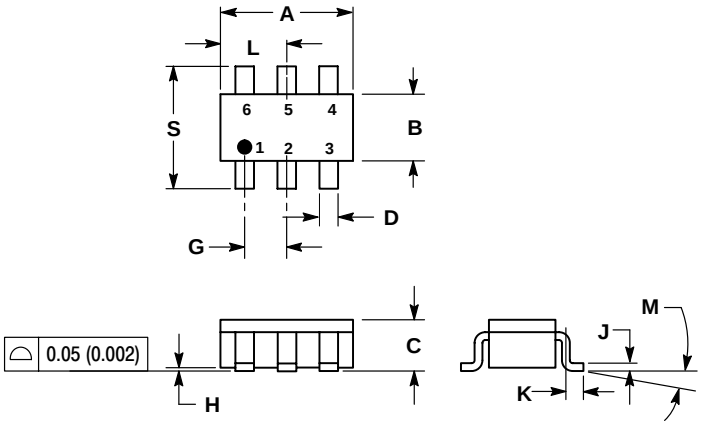
Use the Device Number to order the 7 inch/3,000 unit reel.

Replace the “T1” with “T3” in the Device Number to order the 13 inch/10,000 unit reel.

MMQA Quad Common Anode Series

PACKAGE DIMENSIONS

SC−74
CASE 318F−05
ISSUE K

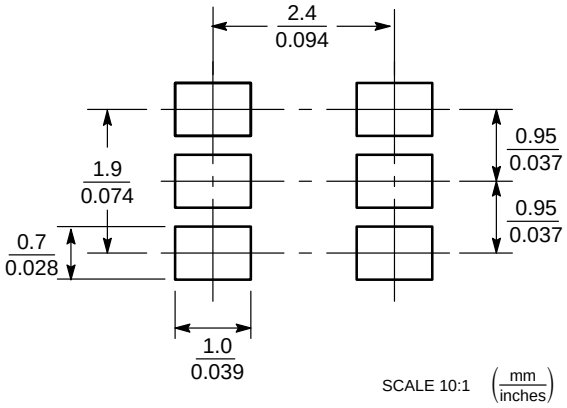


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318F−01, −02, −03 OBSOLETE. NEW STANDARD 318F−04.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.1142	0.1220	2.90	3.10
B	0.0512	0.0669	1.30	1.70
C	0.0354	0.0433	0.90	1.10
D	0.0098	0.0197	0.25	0.50
G	0.0335	0.0413	0.85	1.05
H	0.0005	0.0040	0.013	0.100
J	0.0040	0.0102	0.10	0.26
K	0.0079	0.0236	0.20	0.60
L	0.0493	0.0649	1.25	1.65
M	0 °	10 °	0 °	10 °
S	0.0985	0.1181	2.50	3.00

STYLE 1:
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. CATHODE
5. ANODE
6. CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
Fax: 303−675−2176 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

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Japan: ON Semiconductor, Japan Customer Focus Center
2−9−1 Kamimeguro, Meguro−ku, Tokyo, Japan 153−0051
Phone: 81−3−5773−3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.